

NOT RECOMMENDED FOR NEW DESIGN **CONTACT US**



DMN5L06K

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)}	I _D T _A = +25°C
50V	2.0Ω @ V _{GS} = 5.0V	300mA
	2.5Ω @ V _{GS} = 2.5V	200mA

Features and Benefits

- Low On-Resistance
- Very Low Gate Threshold Voltage (1.0V Max)
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected up to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High-Reliability.

https://www.diodes.com/quality/product-definitions/

An Automotive-Compliant Part is Available Under Separate Datasheet (DMN5L06KQ)

Description and Applications

This new generation 50V N-channel enhancement mode MOSFET is designed to minimize RDS(ON) yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switches.

- Load switches
- Level switches

Mechanical Data

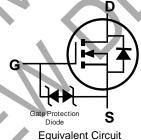
- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Annealed over Alloy 42 Lead-Frame. Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)

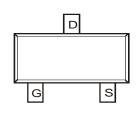




View







Top View

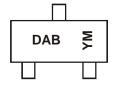
Ordering Information (Note 4)

Part Number		Dookees	Packing			
Part Number	< 1	Package	Qty.	Carrier		
DMN5L06K-7		SOT23	3000	Tape & Reel		

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



DAB = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: J = 2022) M = Month (ex: 9 = September)

Date Code Kev

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Year	2006		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	T		J	K	L	М	N	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain Source Voltage	V _{DSS}	50	V
Gate-Source Voltage	Vgss	±20	V
Drain Current (Note 5) Continuous Pulsed (Note 6)	l _D	300 800	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	350	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	357	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-65 to +150	°C

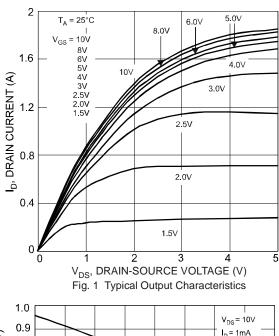
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	\					
Drain-Source Breakdown Voltage	BVDSS	50	_		V	$V_{GS} = 0V$, $I_D = 10\mu A$
Zero Gate Voltage Drain Current @ T _C = +25°0	C I _{DSS}	1		60	nA	$V_{DS} = 50V, V_{GS} = 0V$
Gate-Body Leakage	lgss		-/	1 500 50	μΑ nA nA	$V_{GS} = \pm 12V, V_{DS} = 0V$ $V_{GS} = \pm 10V, V_{DS} = 0V$ $V_{GS} = \pm 5V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	0.49	-	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
Static Drain-Source On-Resistance	R _{DS(ON)}		2.71 1.56 1.19	3.0 2.5 2.0	Ω	$V_{GS} = 1.8V, I_{D} = 50mA$ $V_{GS} = 2.5V, I_{D} = 50mA$ $V_{GS} = 5.0V, I_{D} = 50mA$
On-State Drain Current	Id(on)	0.5	1.4	_	Α	Vgs = 10V, Vps = 7.5V
Forward Transconductance	Y _{fs}	200	_	_	mS	$V_{DS} = 10V, I_D = 0.2A$
Source-Drain Diode Forward Voltage	V _{SD}	0.5	0.7	1.4	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss			50	pF	.,
Output Capacitance	Coss		_	25	pF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	_	5.0	pF	1 - 1.0WII IZ

Notes:

- 5. Device mounted on FR-4 PCB.
 6. Pulse width ≤ 10ms, duty cycle ≤ 1%.
 7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to product testing.





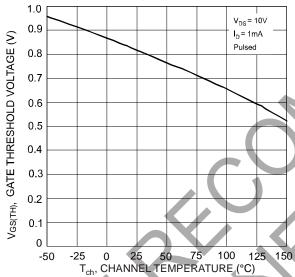


Fig. 3 Gate Threshold Voltage vs. Channel Temperature

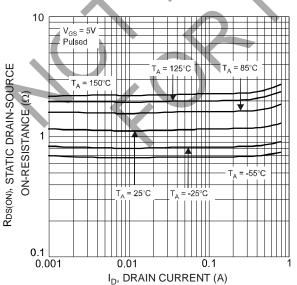
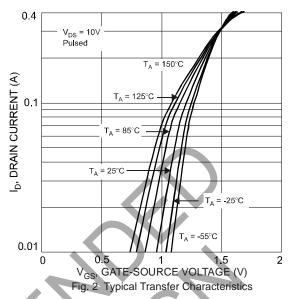


Fig. 5 Static Drain-Source On-Resistance vs. Drain Current



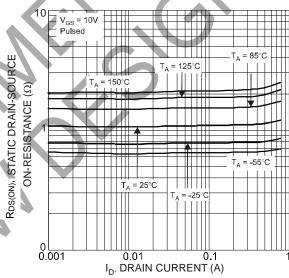


Fig. 4 Static Drain-Source On-Resistance vs. Drain Current

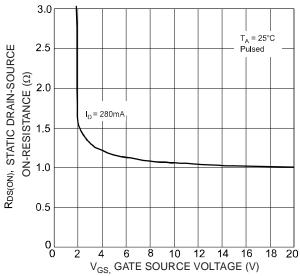


Fig. 6 Static Drain-Source On-Resistance vs. Gate-Source Voltage



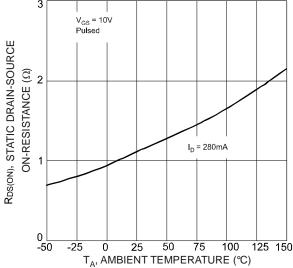
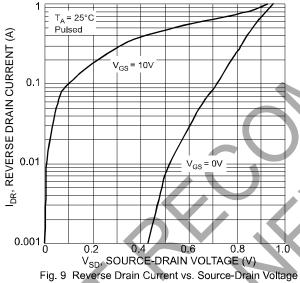
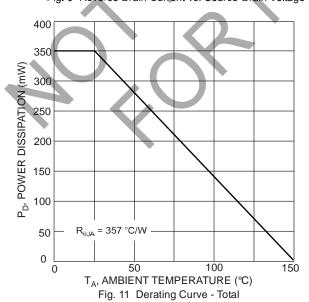
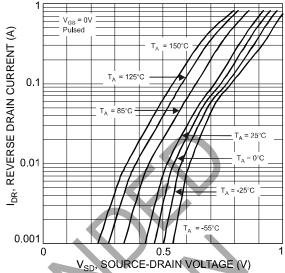


Fig. 7 Static Drain-Source On-State Resistance vs. Ambient Temperature







8 Reverse Drain Current vs. Source-Drain Voltage

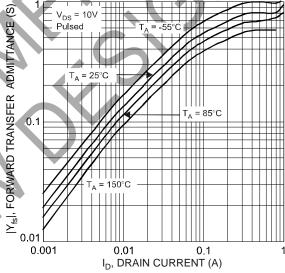
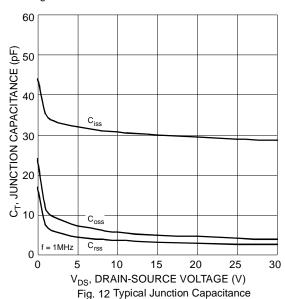


Fig. 10 Forward Transfer Admittance vs. Drain Current

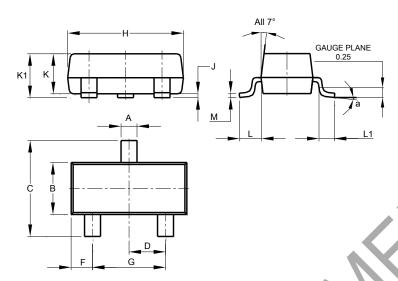




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

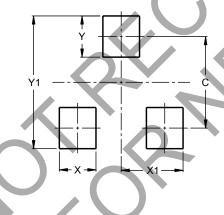


SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
C	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
Ð	1.78	2.05	1.83			
Ŧ	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.890	1.00	0.975			
K1	0.903	1.10	1.025			
F	0.45	0.61	0.55			
<u>L</u>	0.25	0.55	0.40			
М	0.085	0.150	0.110			
а	0°	8°				
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.9



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